MS32 Switching Sensor

- **AMR Switching-Sensor**
- **TDFN Outline 2.5x2.5x0.8 mm^3**
- **Temperature Compensated Switching Point**
- **Low Power Consumption**

DESCRIPTION

The MS32 is a magnetic field sensor which is built in the form of a Wheatstone bridge. Each of its four resistors is made from *Permalloy,* a material that shows the *anisotropic magneto resistance effect*. An unidirectional magnetic field in the surface parallel to the chip (x-y plane) along the y-axis will deliver a field dependent output signal. A **magnetic switching point**, which is almost **independent on temperature** is typically set to Hs=1.85 kA/m. In addition, the characteristic curve is linear over a wide magnetic field range. Thus, the new MS32 simplifies the adaption of the sensor to different mechanical and magnetical environments. The sensor die is packaged in a modern TDFN package.

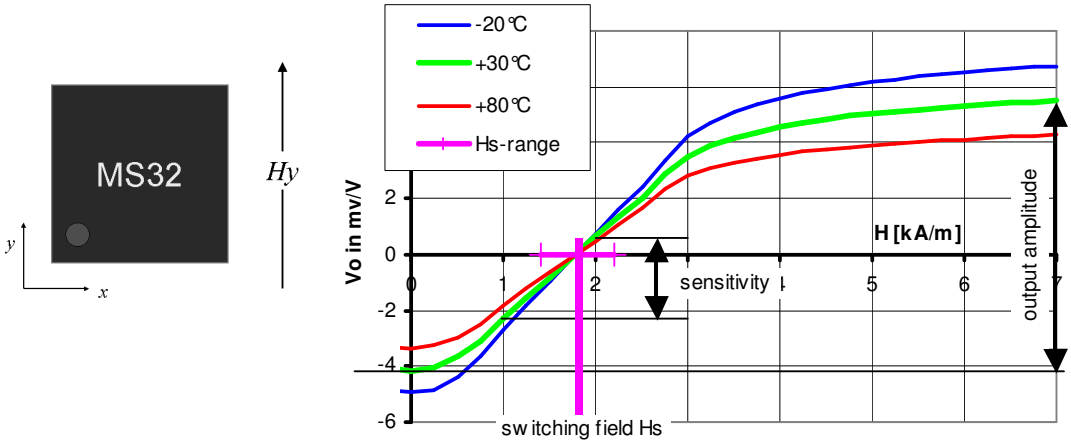


***Figure 1**: Characteristic curves for MS32 at different ambient temperatures (-20℃, +30℃, +80℃)*

FEATURES

- Sensor based on solid state magnetoresistance effect
- Unipolar signal output
- Linear field response
- High sensitivity, low hysteresis
- Temperature compensated switching point
- Low power consumption due to high bridge resistance
- Supply voltage up to 30 V
- Small TDFN package

APPLICATIONS

- Contactless position detection (presence, open/close)
- Industrial
- Consumer
- Automotive

Applications, like:

- Small stroke pneumatic cylinders
- Cover positions of Notebooks and Mobiles
- Doors, windows etc.

CHARACTERISTIC VALUES

Parameter	Condition	Symbol	Min	Typ	Max	Unit
Mechanical dimensions						
Length		X		**2.5**		mm
Width		Y		**2.5**		mm
Height		Z		**0.75**		mm
Pad size	7)			**0.25 x 0.30**		mm^2
Operating limits						
Max. supply voltage		$V_{CC, MAX}$			**30**	V
Operating temperature		T_{OP}	**-25**		**+85**	℃
Storage temperature		T_{ST}	**-25**		**+125**	℃

Stress above one or more of the limiting values may cause permanent damage to the device. Exposure to limiting values for extended periods may affect device reliability.

Parameter	Condition	Symbol	Min	Typ	Max	Unit
Sensor specification (V_{CC} = 5 V, T = 30 ℃)						
Supply voltage		V_{CC}		**5**	**30**	kA/m
Resistance		R_B	**10300**	**11500**		□
Offset		V_{OFF}/V_{CC}		**-4**	**-1.5**	mV/V
Sensitivity	1)	S	**2**	**3**		(mV/V)/(kA/m)
Output amplitude	2)	V_{MAX}	**8**			mV/V
Hysteresis (@ V_0=0) 3)		Hyst.			**0.9**	mV/V
Sensor specification (T = -25 ℃; +85℃; Conditions A & B) [6]						
TC of amplitude		TCSV	**-0.36**	**-0.32**	**-0.28**	%/K
TC of bridge resistance		TCBR	**+0.27**	**+0.32**	**+0.37**	%/K
Switching field 5)	4)	Hs	**1.40**	**1.85**	**2.30**	kA/m

All parameters are measured on wafer level.
1) average gradient in the range 1.0 - 2.0 kA/m
2) difference between output voltage/supply voltage measured at H = 7 kA/m and H = 0 kA/m
3) hysteresis [in kA/m] = hysteresis [in mV/V] /S
4) switching voltage = 0 mV/V
5) switching field = magnetic field at switching voltage
6) values at –25℃ can be determined by linear extrapolation from +30℃- and +85℃-values.
7) recommended solder reflow process according to IPC/JEDEC J-STD-020D (Pb-Free Process)

MEASUREMENT CONDITIONS

Parameter	Symbol	Unit	Condition
A. Set Up Conditions			
ambient temperature	T	℃	T = 23 +/- 5 ℃ (unless otherwise noted)
supply voltage	V_{CC}	V	V_{CC} = 5 V
applied magnetic field	H_Y	kA/m	H_Y = -7 .. +7 kA/m; along y-direction; $\|H_X\|$ < 100 A/m Pre-magnetization along x-direction with H_X >= 3 kA/m
B. Parameter Definitions (T= -25 ℃, +85 ℃) see characteristic values [6)]			
ambient temperatures	T	℃	T_1 = -25 , T_0 = +30 , T_2 = +85 ℃
TC of amplitude	TCSV	%/K	$TCV = \frac{1}{(T_2 - T_1)} \cdot \frac{V_a(T_2) - V_a(T_1)}{V_a(T_1)} \cdot 100\%$
TC of resistance	TCBR	%/K	$TCR = \frac{1}{(T_2 - T_1)} \cdot \frac{R(T_2) - R(T_1)}{R(T_1)} \cdot 100\%$
TC of offset	TCV_{OFF}	µV/(VK)	$TCVoff = \frac{Voff(T_2) - Voff(T_1)}{(T_2 - T_1)}$

BLOCK DIAGRAM

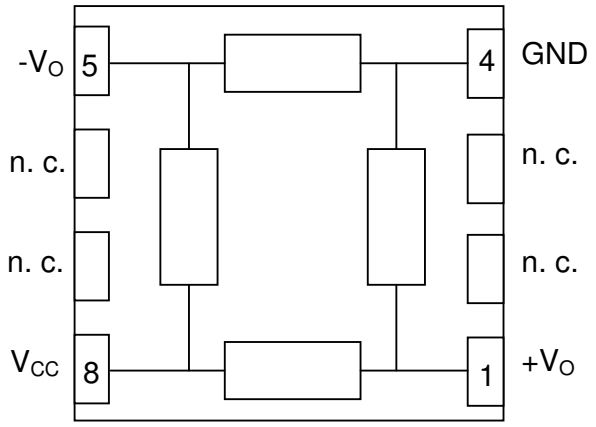


Figure 2: *internal and external connections (TDFN, Chip)*

SENSOR OUTLINE

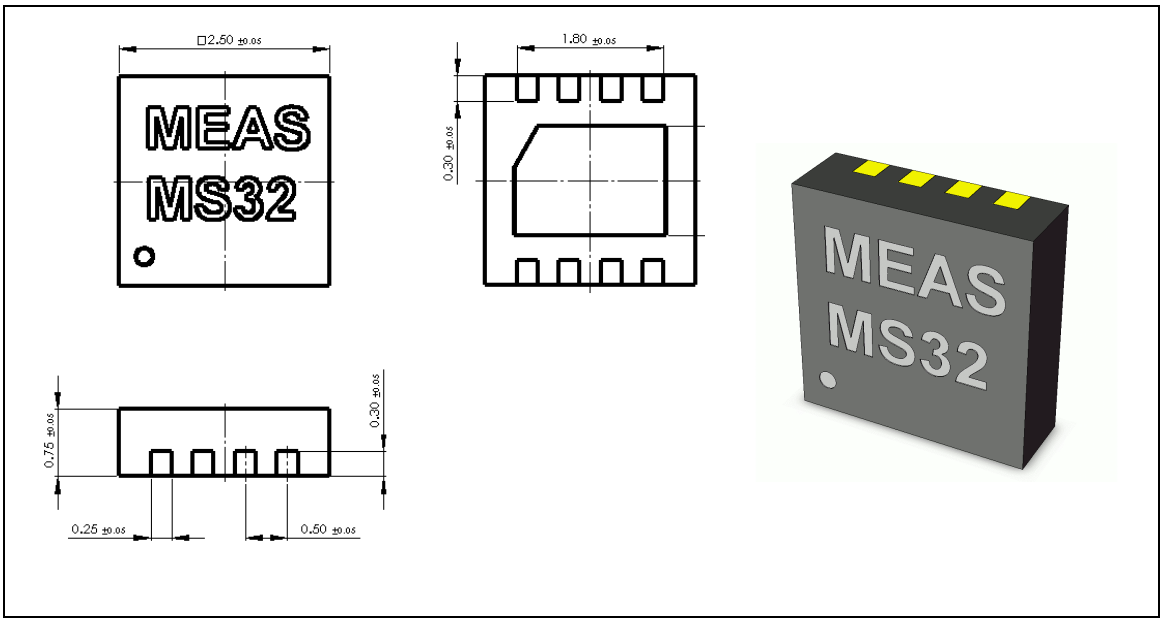
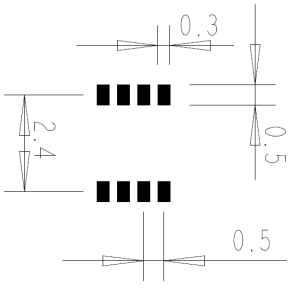


Figure 3: *TDFN-package outline*

Pin assignment:

Pin	Symbol	Function
1	$+V_O$	positive output bridge
2	n. c.	not connected
3	n. c.	not connected
4	GND	ground
5	$-V_O$	negative output bridge
6	n. c.	not connected
7	n. c.	not connected
8	V_{CC}	supply voltage bridge

Recommended Solder Pad Layout:



Note:

Pin 1 position is marked by a dot on the top side and by the chamfered corner of the bottom plate.
The bottom plate is designated to be a heat sink. It has no electrical connection to any pin.
The sensitive area is positioned in the center of the package.

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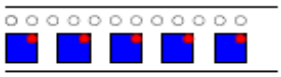
TAPE AND REEL PACKAGING INFORMATION

Description	Reel size	Units/reel	Pin 1 orientation	Note
MS32	7”	3,000	Top-right of sprocket hole side	

ORDERING CODE

Device	Package	MOQ	Part number
MS32 die	Wafer / undiced	1 wafer	*on request*
MS32	TDFN 2.5 x 2.5	1 reel	**G-MRCO-017**

ORDERING INFORMATION

Measurement Specialties, Inc. 1000 Lucas Way Hampton, VA 23666 Tel: 1-800-555-1551 Fax: 1-757-766-4297 Email: sales@meas-spec.com Web: www.meas-spec.com	Europe MEAS Deutschland GmbH Hauert 13, D-44227 Dortmund, Germany. Phone: +49-(0)231-9740-0 Fax: +49-(0)231-9740-20 Email: info.de@meas-spec.com Web: www.meas-spec.com	Measurement Specialties China Ltd. No. 26, Langshan Road, Shenzhen High-tech Park (North) Nanshan District, Shenzhen, China 518107 Phone: +86-755-33305088 Fax: +86-755-33305099 Email: info.cn@meas-spec.com Web: www.meas-spec.com